



Recirculating ERL Filling Pattern Study

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Filling Patterns



Simple 6-turn recirculating linac with 1 bunch train.

6 turns = 3 accelerations + 3 decelerations

Only 1 bunch is injected per turn to minimize voltage fluctuation by beamloading.

Filling pattern describes injection order: which bunch goes to which bucket.

Filling pattern [1 4 3 6 5 2]: 1st bucket filled in 1st turn 2nd bucket filled in 4th turn 3rd bucket filled in 3rd turn 4th bucket filled in 6th turn 5th bucket filled in 5th turn 6th bucket filled in 2nd turn

Bunch phase changes by 180° every 3 turns.

RF Bucke	et# 1	2	3	4	5	6
Turn# 1	M	\mathcal{M}	\mathcal{M}	\mathcal{M}	\bigwedge	\mathbf{M}
2			🗣 🚽 🤍			2
3	Î	\mathcal{M}	ß	\bigwedge	\bigwedge	
4		A	ß	\mathcal{M}	\bigwedge	
5		Å		\bigwedge		
6	\int	M		M	M	



Beamloading Patterns

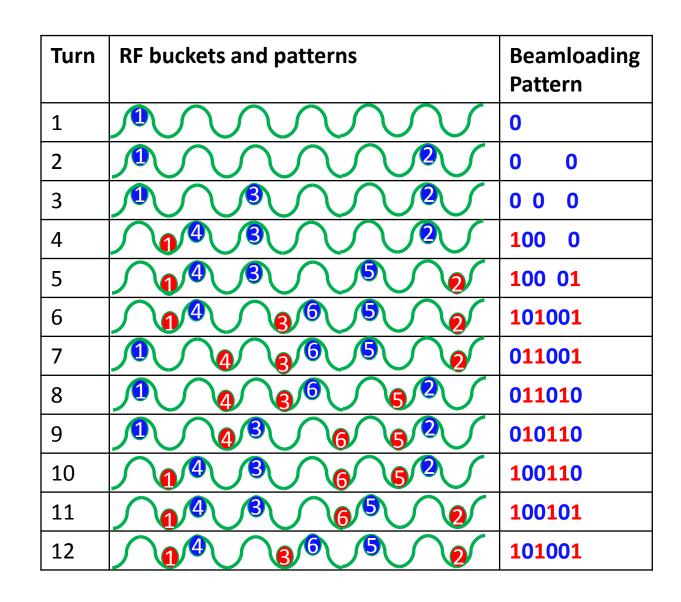


Fill patterns generate beamloading patterns.

Beamloading type: Accelerating & Decelerating

Acceleration takes voltage from cavity: -1 Deceleration adds voltage to cavity: 1

Modes	Beamloading Notation	Binary Notation
Acceleration	-1	0
Deceleration	1	1





Beamloading Pattern Periodicity



In simple recirculating linac, the beamloading pattern changes every turn.

- N-turn recirculating ERL:
 - N bunches form a train
 - Ring can be filled with many similar trains
 - Total of (N-1)! fill patterns
 - 120 patterns for 6-turn
- Beamloading patterns repeats with N-turn period.

	Turn #	123456	142365	143652	
	1	011100	101100	011001	
	2	001110	011100	011010	
	3	000111	010101	010110	
	4	100011	010011	100110	
	5	110001	100011	100101	
	6	111000	101010	101001	
	7	011100	101100	011001	
	8	001110	011100	011010	\checkmark
	9	000111	010101	010110	

Note: N-turn = (accelerating turns) + (decelerating turns)





Fill pattern \rightarrow beamloading pattern \rightarrow cavity voltage change. Different fill patterns \rightarrow different cavity voltage fluctuations.

$$V_{ji} = \sum_{j=1}^{N} \boldsymbol{B}_{j} \left(\boldsymbol{F}_{i} \right)$$

F_i: *i*th Fill pattern

Beam Loading Pattern in the jth turn
V_j: Voltage in the jth turn
N: number of bunches in a train.

	F ₁ : 123456			<i>F₆₀</i> : 143652		
J th turn	B _j	V _j	\overline{V}_{turn}	B _j	V _j	\overline{V}_{turn}
1	100011	᠕ᢧ	-0.5	100110	ഹഹ	0.17
2	110001	᠕	-1.5	100101	പസ്പ	- 0.17
3	111000	<i>ک</i> ٹر	-0.5	101001	᠕᠕	0.17
4	011100	-	0.5	011001	᠕᠕	- 0.17
5	001110	᠂᠕᠕	1.5	011010	ഹസ	0.17
6	000111	᠂ᢅ᠕	0.5	010110	൝	-0.17
$\sigma_{\overline{V}_{turn}}$	0.96			0.1667		
σ_V/N	1.3540/6 = 0.23			$\frac{1}{\sqrt{2}}/6 = 0.12$		





Static setpoint:

- feedback voltage setpoint is set to a constant value
- LLRF makes corrections to all voltage changes

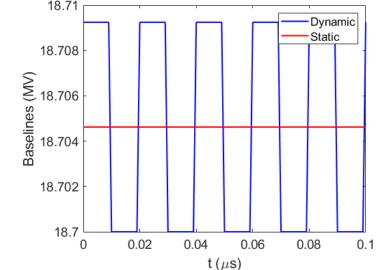
Dynamic setpoint:

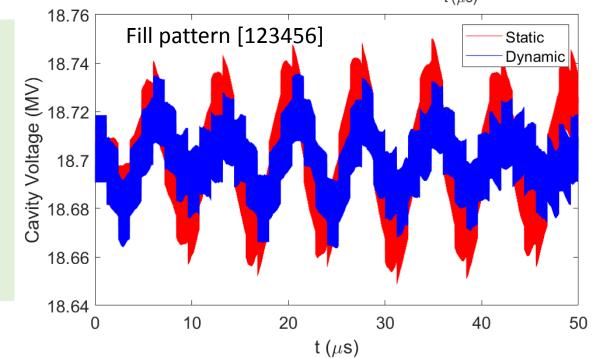
- feedback voltage setpoint changes dynamically according to the expected voltage change due to the beamloading
- LLRF makes corrections to non-beamloading voltage changes only

Voltage change by beamloading is corrected by itself later, so no need for correction.

In static setpoint, LLRF system tries to fight itself during beamloading!

Dynamic setpoint is better.







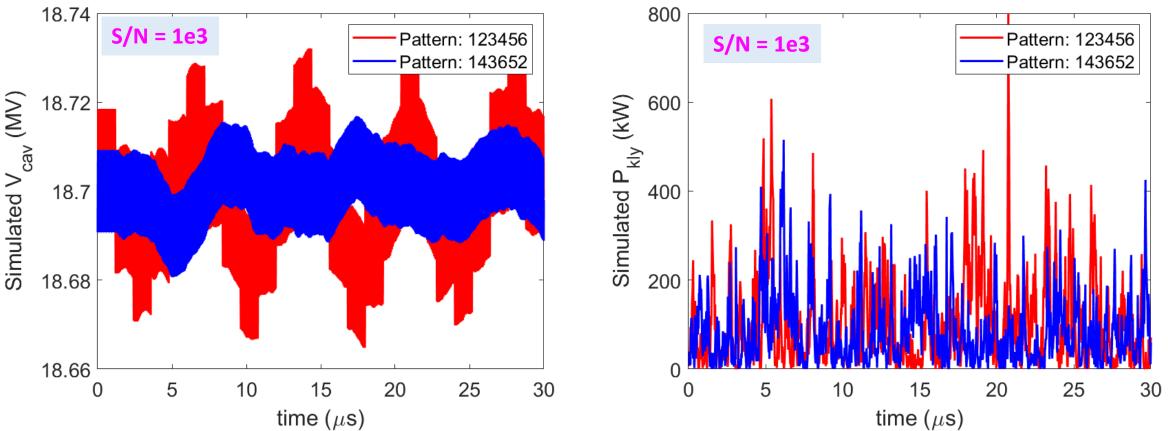
Pattern Matters for RF Stability



Fill patterns matter for RF stability.

Some patterns are better because they create less cavity voltage fluctuation and requires less power from klystron to maintain stable cavity voltage.

Beamloading simulation: beam interaction with cavity and RF system; dynamic setpoint and with noise.





Pattern Matters for RF Stability

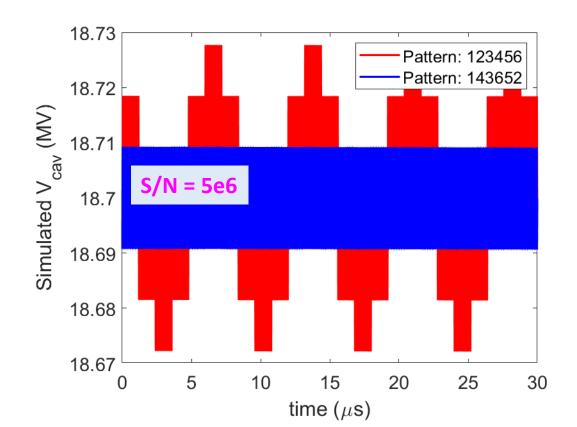


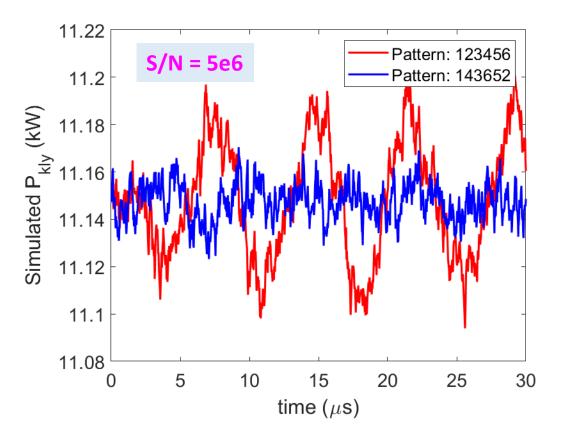
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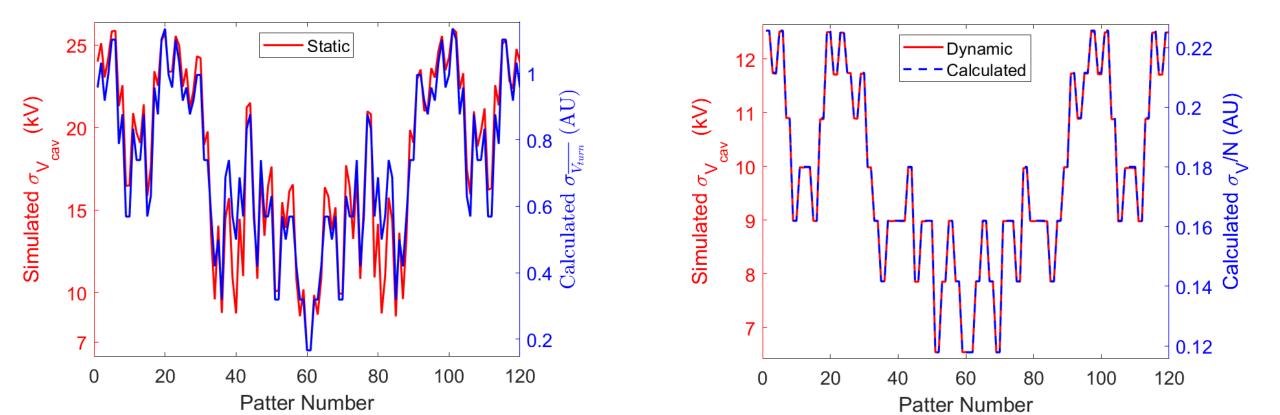
Scanned all 120 fill patterns in simulation without noise.

Found optimal patterns with least RF jitter.

Patterns #60 & #61 are optimal for both static and dynamic setpoints.

Patterns optimal for dynamic setpoint: 143652 (#60), 145236 (#61), 142536, 142563, 143625, 145263, 146325, and 146352.

LLRF feedback effects optimal pattern figure of merit: static $\rightarrow \sigma_{\overline{V}_{turn}}$; dynamic $\rightarrow \frac{\sigma_V}{N}$.





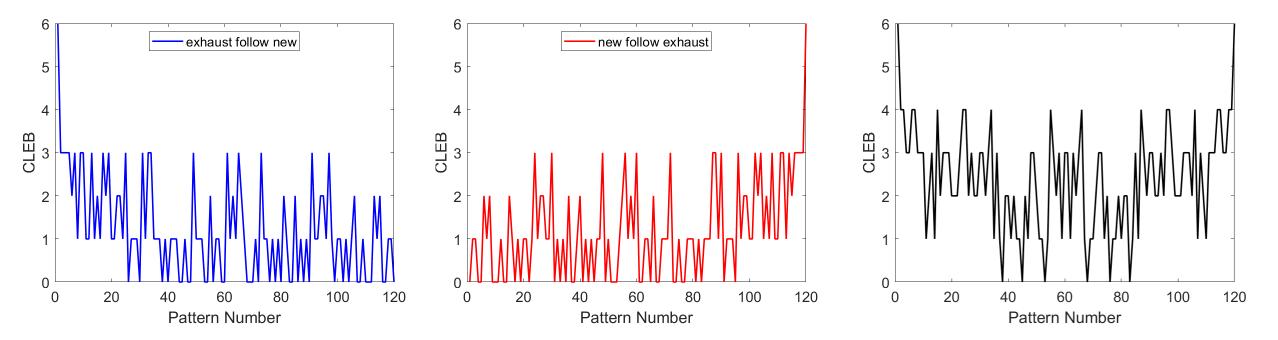


Low energy particles are more susceptible to multi-bunch effect: $\propto \beta/E$.

Avoid Consecutive Low Energy Bunches (CLEB) to maximize threshold current [1].

Good CLEB: exhaust bunch follows new bunch; second bunch is dumped on this turn.

Bad CLEB: new bunch follows exhaust bunch.



[1] D. Angal-Kalinin, et al., PERLE: Powerful Energy Recovery LINAC for Experiments - Conceptual Design Report, https://arxiv.org/abs/1705.08783





- Studying the effect of:
 - different topologies
 - injection timing
 - ring circumference
 - off-crest beam loading phases
- More detailed BBU studies.
- Optimal LLRF requirements.





- Developed mathematical construct to analyze bunches over many turns.
- This can be applied to different scenarios like RF stability and BBU.
- Our studies show that LLRF requires dynamic setpoint and it is highly sensitive to noise.
- We welcome any comments.





THE END

Thanks for your attention!

Comments & Questions?